NSN 5961-01-418-4017

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-418-4017 **Inclosure Material:** Plastic **Overall Length:** 0.620 inches **Overall Height:** 0.190 inches **Overall Width:** 0.405 inches **End Application:** An/usm-44 (v) 5 **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220ac **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 working peak reverse voltage **Current Rating Per Characteristic:** 15.00 amperes forward current, average and 15.00 amperes forward current, average blank and 200.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: